RS1AFA, NRVHPRS1AFA **Series**

Surface Mount Fast Recovery Rectifiers

0.8 A, 50 V - 1000 V

Features

- Glass Passivated Chip Junction
- Fast Switching for High Efficiency
- High Surge Capacity
- Low Forward Voltage: 1.3 V Maximum
- UL Flammability 94V-0 Classification
- MSL 1 per J-STD-020
- RoHS Compliant / Green Molding Compound
- Industrial Device Qualified per AEC-Q101 Standards
- NRVHP Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable



ON Semiconductor®

www.onsemi.com





SOD-123FA CASE 425AB

(Color Band Denotes Cathode)

ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method [†]
RS1AFA	RAL	SOD-123FA	Tape and Reel
RS1BFA	RBL	SOD-123FA	Tape and Reel
RS1DFA	RDL	SOD-123FA	Tape and Reel
RS1GFA	RGL	SOD-123FA	Tape and Reel
RS1JFA	RJL	SOD-123FA	Tape and Reel
RS1KFA	RKL	SOD-123FA	Tape and Reel
RS1MFA	RML	SOD-123FA	Tape and Reel
NRVHPRS1AFA	RAL	SOD-123FA	Tape and Reel
NRVHPRS1BFA	RBL	SOD-123FA	Tape and Reel
NRVHPRS1DFA	RDL	SOD-123FA	Tape and Reel
NRVHPRS1GFA	RGL	SOD-123FA	Tape and Reel
NRVHPRS1JFA	RJL	SOD-123FA	Tape and Reel
NRVHPRS1KFA	RKL	SOD-123FA	Tape and Reel
NRVHPRS1MFA	RML	SOD-123FA	Tape and Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

1

^{*}See authorized use policy

RS1AFA, NRVHPRS1AFA Series

Table 1. ABSOLUTE MAXIMUM RATINGS Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

		Value							
Symbol	Parameter	RS1 AFA	RS1 BFA	RS1 DFA	RS1 GFA	RS1 JFA	RS1 KFA	RS1 MFA	Unit
V_{RRM}	Repetitive Peak Reverse Voltage	50	100	200	400	600	800	1000	V
V _{RMS}	RMS Reverse Voltage	35	70	140	280	420	560	700	V
V_{R}	DC Blocking Voltage	50	100	200	400	600	800	1000	V
I _{F(AV)}	Average Forward Rectified Current				0.8	•	•	•	Α
I _{FSM}	Peak Forward Surge Current: 8.3 ms Single Half Sine-Wave Superimposed on Rated Load		30					Α	
TJ	Operating Junction Temperature Range		−55 to +150					°C	
T _{STG}	Storage Temperature Range		−55 to +150						°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 2. THERMAL CHARACTERISTICS (Note 1)

Symbol	Parameter	Value	Unit
$\Psi_{\sf JL}$	Typical Thermal Characteristics, Junction-to-Lead	32	°C/W
$R_{\theta JA}$	Typical Thermal Resistance, Junction-to-Ambient	105	°C/W

^{1.} Device mounted on 5 mm x 5 mm Cu pad PCB.

Table 3. ELECTRICAL CHARACTERISTICS Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter		Min	Тур	Max	Unit	
V _F	Instantaneous Forward Voltage (Note 2)				1.3	V	
I _R	Reverse Current at Rated V _R	T _J = 25°C				5	μΑ
					50		
CJ	Junction Capacitance	V _R		10		pF	
T _{rr}	Reverse Recovery Time	I _F = 0.5 A,	RS1AFA, RS1BFA, RS1DFA			150	ns
		I _R = 1 A, I _{rr} = 0.25 A	RS1GFA, RS1JFA			250	
			RS1KFA, RS1MFA			500	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{2.} Pulse test with PW = 300 μ s, 1% duty cycle

RS1AFA, NRVHPRS1AFA Series

TYPICAL PERFORMANCE CHARACTERISTICS

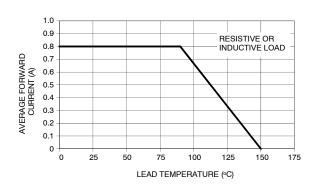


Figure 1. Forward Current Derating Curve

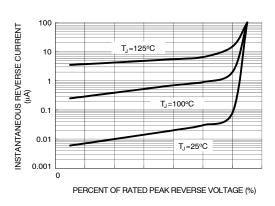


Figure 2. Typical Reverse Characteristics

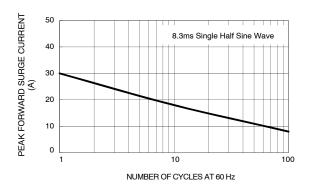


Figure 3. Maximum Non-Repetitive Forward Surge Current

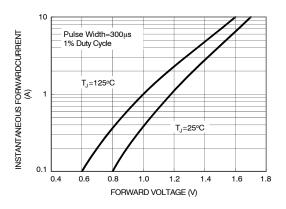


Figure 4. Typical Instantaneous Forward Characteristics

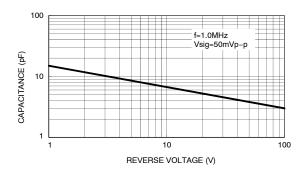


Figure 5. Typical Junction Capacitance

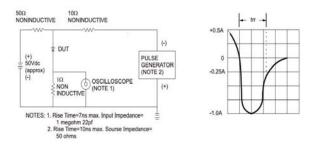
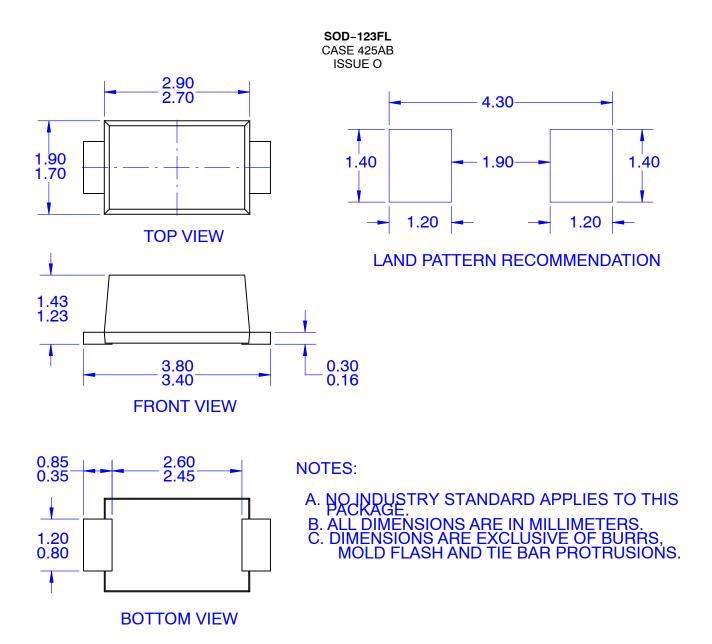


Figure 6. Reverse Recovery Time Characteristic and Test Circuit Diagram

RS1AFA, NRVHPRS1AFA Series

PACKAGE DIMENSIONS



ON Semiconductor and ill are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns me rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any product herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semicondu

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

ПОСТАВКА ЭЛЕКТРОННЫХ КОМПОНЕНТОВ

многоканальный

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

Данный компонент на территории Российской Федерации Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г. Москва, ул. Щербаковская д. 3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru moschip.ru_6 moschip.ru 4 moschip.ru 9